



VN31

ISO HIGH SIDE SMART POWER SOLID STATE RELAY

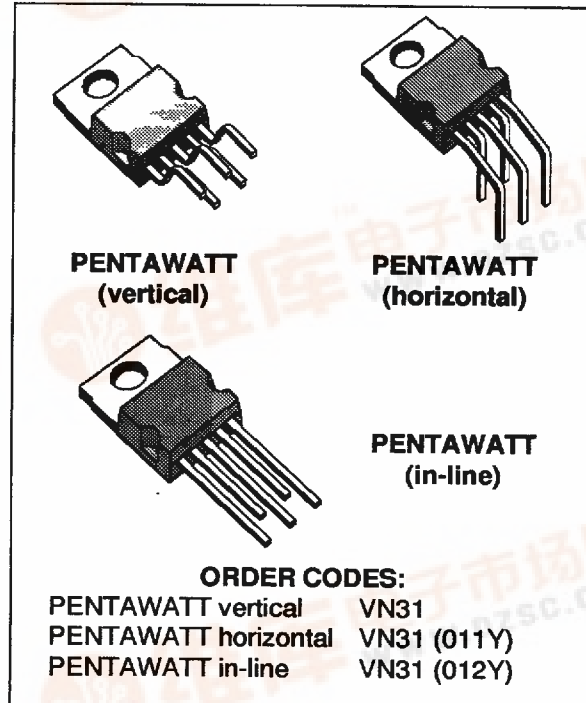
PRELIMINARY DATA

TYPE	V _{DSS}	R _{DS(on)}	I _n (*)	V _{CC}
VN31	60 V	0.03 Ω	11.5 A	26 V

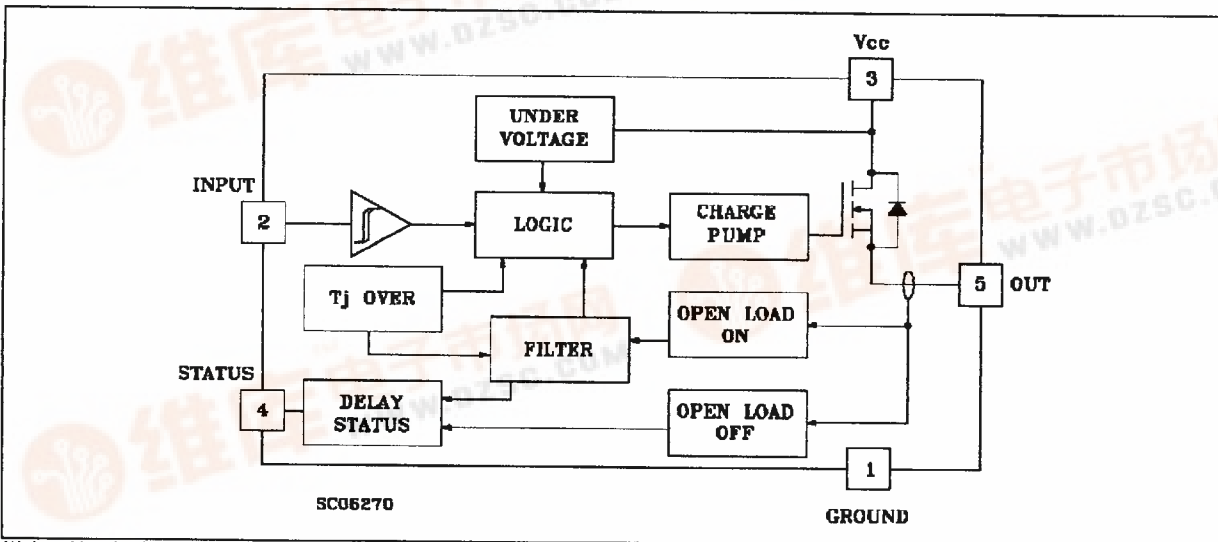
- MAXIMUM CONTINUOUS OUTPUT CURRENT (#): 31 A @ T_c= 85°C
- 5V LOGIC LEVEL COMPATIBLE INPUT
- THERMAL SHUT-DOWN
- UNDER VOLTAGE PROTECTION
- OPEN DRAIN DIAGNOSTIC OUTPUT
- INDUCTIVE LOAD FAST DEMAGNETIZATION
- VERY LOW STAND-BY POWER DISSIPATION

DESCRIPTION

The VN31 is a monolithic device made using SGS-THOMSON Vertical Intelligent Power Technology, intended for driving resistive or inductive loads with one side grounded. Built-in thermal shut-down protects the chip from over temperature and short circuit. The open drain diagnostic output indicates: open load in off state and in on state, output shorted to V_{CC} and overtemperature. Fast demagnetization of inductive loads is achieved by negative (-18V) load voltage at turn-off.



BLOCK DIAGRAM

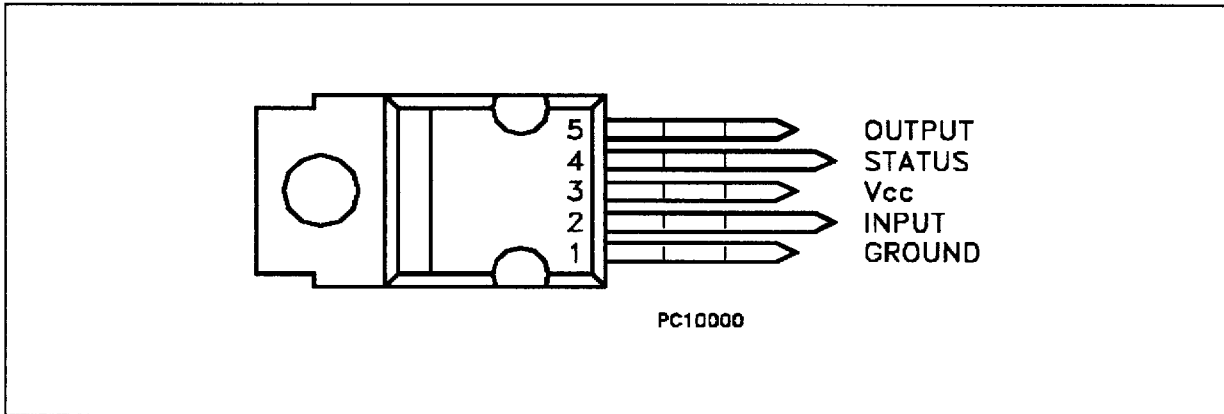


(*) I_n = Nominal current according to ISO definition for high side automotive switch (see note 1)
 (#) The maximum continuous output current is the current at T_c = 85 °C for a battery voltage of 13 V which does not activate self protection

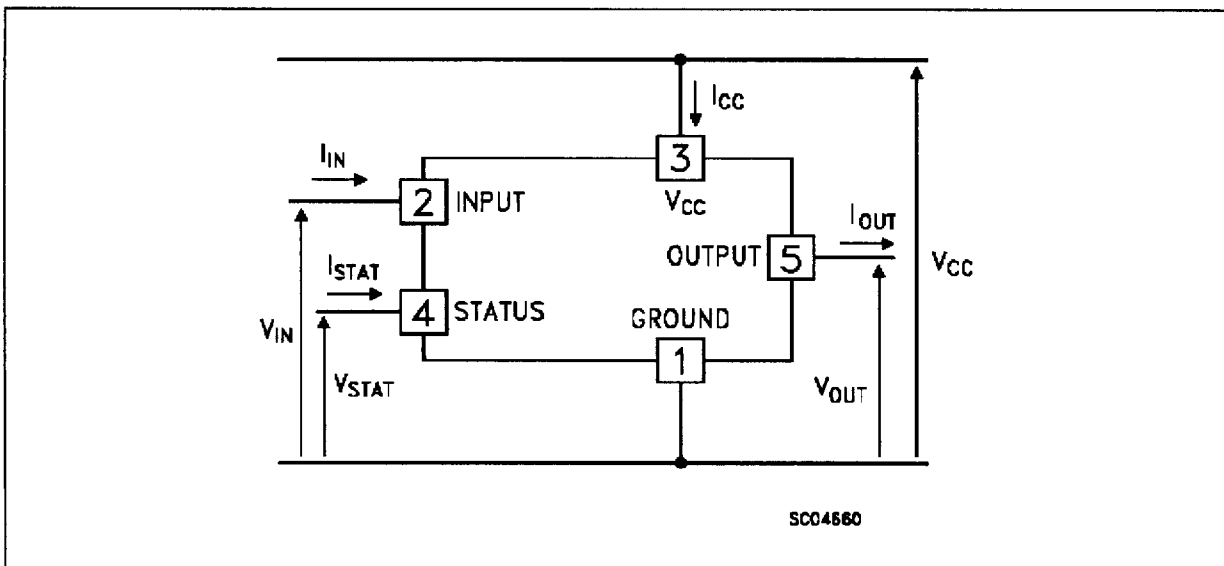
ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Unit
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	60	V
I_{OUT}	Output Current (cont.) at $T_c = 85\text{ }^\circ\text{C}$	31	A
I_R	Reverse Output Current at $T_c = 85\text{ }^\circ\text{C}$	-31	A
I_{IN}	Input Current	± 10	mA
$-V_{CC}$	Reverse Supply Voltage	-4	V
I_{STAT}	Status Current	± 10	mA
V_{ESD}	Electrostatic Discharge (1.5 k Ω , 100 pF)	2000	V
P_{tot}	Power Dissipation at $T_c = 85\text{ }^\circ\text{C}$	54	W
T_j	Junction Operating Temperature	-40 to 150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55 to 150	$^\circ\text{C}$

CONNECTION DIAGRAM



CURRENT AND VOLTAGE CONVENTIONS



THERMAL DATA

$R_{thj-case}$	Thermal Resistance Junction-case	Max	1.2	$^{\circ}C/W$
$R_{thj-amb}$	Thermal Resistance Junction-ambient	Max	60	$^{\circ}C/W$

ELECTRICAL CHARACTERISTICS ($V_{CC} = 13 V$; $-40 \leq T_J \leq 125 ^{\circ}C$ unless otherwise specified)

POWER

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{CC}	Supply Voltage		5.5	13	26	V
$I_n(^{\wedge})$	Nominal Current	$T_c = 85 ^{\circ}C$ $V_{DS(on)} \leq 0.5$ (note 1)	11.5			A
R_{on}	On State Resistance	$I_{OUT} = 11.5 A$ $I_{OUT} = 11.5 A$ $T_J = 25 ^{\circ}C$			0.06 0.03	Ω Ω
I_s	Supply Current	Off State $T_J \geq 25 ^{\circ}C$ On State			50 15	μA mA
$V_{DS(MAX)}$	Maximum Voltage Drop	$I_{OUT} = 25 A$ $T_c = 85 ^{\circ}C$			1.5	V

SWITCHING

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}(^{\wedge})$	Turn-on Delay Time Of Output Current	$I_{OUT} = 11.5 A$ Resistive Load Input Rise Time $< 0.1 \mu s$		90		μs
$t_r(^{\wedge})$	Rise Time Of Output Current	$I_{OUT} = 11.5 A$ Resistive Load Input Rise Time $< 0.1 \mu s$		100		μs
$t_{d(off)}(^{\wedge})$	Turn-off Delay Time Of Output Current	$I_{OUT} = 11.5 A$ Resistive Load Input Rise Time $< 0.1 \mu s$		140		μs
$t_f(^{\wedge})$	Fall Time Of Output Current	$I_{OUT} = 11.5 A$ Resistive Load Input Rise Time $< 0.1 \mu s$		50		μs
$(di/dt)_{on}$	Turn-on Current Slope	$I_{OUT} = 11.5 A$ $I_{OUT} = I_{OV}$		0.08	0.5 1	A/ μs A/ μs
$(di/dt)_{off}$	Turn-off Current Slope	$I_{OUT} = 11.5 A$ $I_{OUT} = I_{OV}$		0.2	3 3	A/ μs A/ μs
V_{demag}	Inductive Load Clamp Voltage	$I_{OUT} = 11.5 A$ $L = 1 mH$	-24	-18	-14	V

LOGIC INPUT

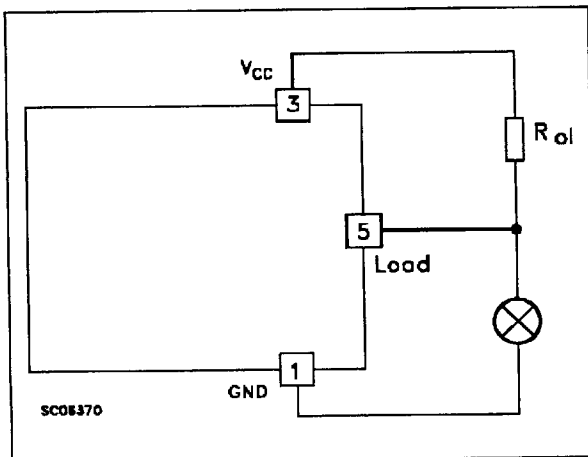
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{IL}	Input Low Level Voltage				0.8	V
V_{IH}	Input High Level Voltage		2		(*)	V
$V_{I(hyst)}$	Input Hysteresis Voltage			0.5		V
I_{IN}	Input Current	$V_{IN} = 5 V$ $V_{IN} = 2 V$ $V_{IN} = 0.8 V$	25	250	500 250	μA μA μA
V_{ICL}	Input Clamp Voltage	$I_{IN} = 10 mA$ $I_{IN} = -10 mA$	5.5	6 -0.7	-0.3	V V

ELECTRICAL CHARACTERISTICS (continued)
PROTECTION AND DIAGNOSTICS (continued)

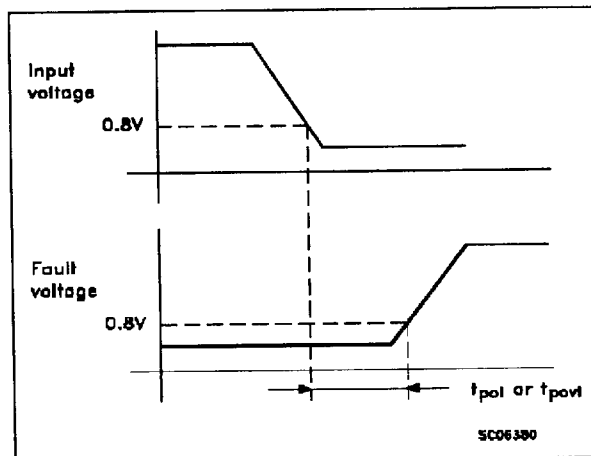
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V _{STAT}	Status Voltage Output Low	I _{STAT} = 1.6 mA			0.4	V
V _{USD}	Under Voltage Shut Down			5		V
V _{SCL}	Status Clamp Voltage	I _{STAT} = 10 mA I _{STAT} = -10 mA		6 -0.7		V V
I _{OV}	Over Current	R _{LOAD} < 10 mΩ -40 ≤ T _c ≤ 125 °C		140		A
I _{AV}	Average Current in Short Circuit	R _{LOAD} < 10 mΩ T _c = 85 °C		2.5		A
I _{OL}	Open Load Current Level		5	600	1250	mA
T _{TSD}	Thermal Shut-down Temperature		140			°C
T _R	Reset Temperature		125			°C
V _{OL}	Open Load Voltage Level	Off-State (note 2)	2.5	3.75	5	V
t _{1(on)}	Open Load Filtering Time	(note 3)	1	5	10	ms
t _{1(off)}	Open Load Filtering Time	(note 3)	1	5	10	ms
t _{2(off)}	Open Load Filtering Time	(note 3)	1	5	10	ms
t _{povl}	Status Delay	(note 3)		5	10	μs
t _{pol}	Status Delay	(note 3)	50	700		μs

(*) See Switching Time Waveforms
 (*) The V_{IH} is internally clamped at 6V about. It is possible to connect this pin to an higher voltage via an external resistor calculated to not exceed 10 mA at the input pin.
 note 1: The Nominal Current is the current at T_c = 85 °C for battery voltage of 13V which produces a voltage drop of 0.5 V
 note 2: I_{OL(off)} = (V_{CC} - V_{OL})/R_{OL} (see figure)
 note 3: t_{1(on)}: minimum open load duration which activates the status output
 t_{1(off)}: minimum load recovery time which desactivates the status output
 t_{2(off)}: minimum on time after thermal shut down which desactivates status output
 t_{povl} t_{pol}: ISO definition (see figure)

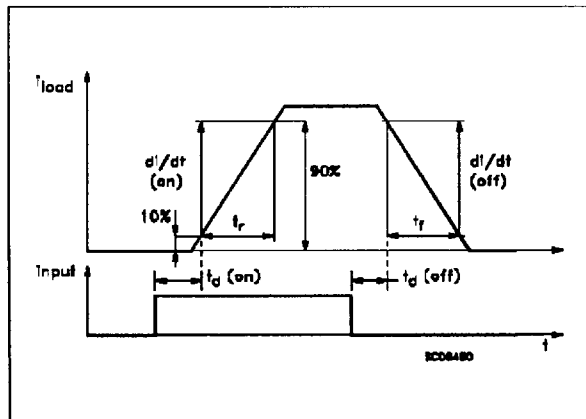
Note 2 Relevant Figure



Note 3 Relevant Figure



Switching Time Waveforms



FUNCTIONAL DESCRIPTION

The device has a diagnostic output which indicates open load conditions in off state as well as in on state, output shorted to V_{CC} and overtemperature. The truth table shows input, diagnostic and output voltage level in normal operation and in fault conditions. The output signals are processed by internal logic. The open load diagnostic output has a 5 ms filtering. The filter gives a continuous signal for the fault condition after an initial delay of about 5 ms. This means that a disconnection during normal operation, with a duration of less than 5 ms does not affect the status output. Equally, any re-connection of less than 5 ms during a disconnection duration does not affect the status output. No delay occur for the status to go low in case of overtemperature conditions. From the falling edge of the input signal the status output initially low in fault condition (over temperature or open load) will go back with a delay (t_{povl}) in case of overtemperature condition and a delay (t_{pol}) in case of open load. These feature fully comply with International Standard Office (I.S.O.) requirement for automotive High Side Driver.

To protect the device against short circuit and over current conditions, the thermal protection turns the integrated Power MOS off at a minimum junction temperature of 140 °C. When the temperature returns to 125 °C the switch is automatically turned on again. In short circuit the protection reacts with virtually no delay, the sensor being located in the region of the die where the heat is generated. Driving inductive loads, an internal function of the

device ensures the fast demagnetization with a typical voltage (V_{demag}) of -18V.

This function allows to greatly reduce the power dissipation according to the formula:

$$P_{dem} = 0.5 \cdot I_{load} \cdot (I_{load})^2 \cdot [(V_{CC} + V_{demag}) / V_{demag}] \cdot f$$

where f = switching frequency and V_{demag} = demagnetization voltage

Based on this formula it is possible to know the value of inductance and/or current to avoid a thermal shut-down. The maximum inductance which causes the chip temperature to reach the shut down temperature in a specific thermal environment, is in fact a function of the load current for a fixed V_{CC} , V_{demag} and f .

PROTECTING THE DEVICE AGAINST LOAD DUMP - TEST PULSE 5

The device is able to withstand the test pulse No. 5 at level II ($V_s = 46.5V$) according to the ISO T/R 7637/1 without any external component. This means that all functions of the device are performed as designed after exposure to disturbance at level II. The VN31 is able to withstand the test pulse No.5 at level III adding an external resistor of 150 ohm between pin 1 and ground plus a filter capacitor of 1000 μF between pin 3 and ground (if $R_{LOAD} \leq 20 \Omega$).

PROTECTING THE DEVICE AGAINST REVERSE BATTERY

The simplest way to protect the device against a continuous reverse battery voltage (-26V) is to insert a Schottky diode between pin 1 (GND) and ground, as shown in the typical application circuit (fig.3).

The consequences of the voltage drop across this diode are as follows:

- If the input is pulled to power GND, a negative voltage of $-V_f$ is seen by the device. (V_{il} , V_{ih} thresholds and V_{stat} are increased by V_f with respect to power GND).
- The undervoltage shutdown level is increased by V_f .

If there is no need for the control unit to handle external analog signals referred to the power GND, the best approach is to connect the reference potential of the control unit to node [1] (see application circuit in fig. 4), which becomes the common signal GND for the whole control board avoiding shift of V_{ih} , V_{il} and V_{stat} . This solution allows the use of a standard diode.

TRUTH TABLE

	INPUT	OUTPUT	DIAGNOSTIC
Normal Operation	L	L	H
	H	H	H
Open Circuit (No Load)	H	H	L
Over-temperature	H	L	L
Under-voltage	X	L	H
Short load to V _{CC}	L	H	L

Figure 1: Waveforms

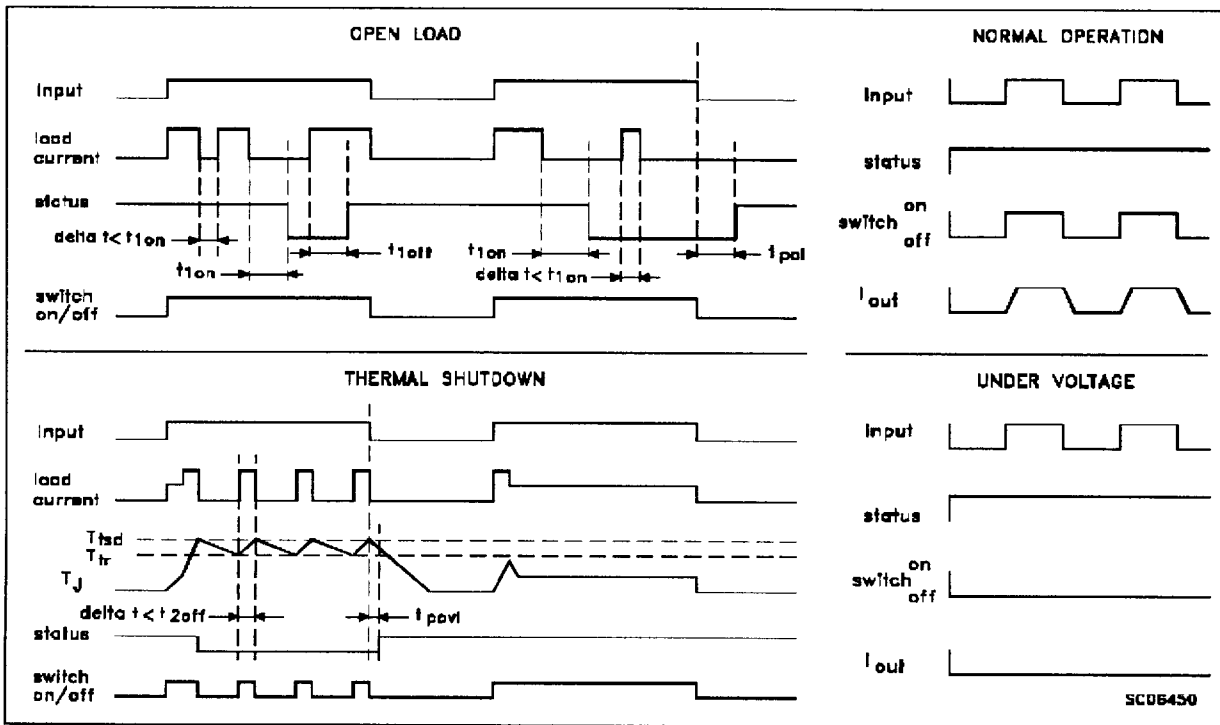


Figure 2: Over Current Test Circuit

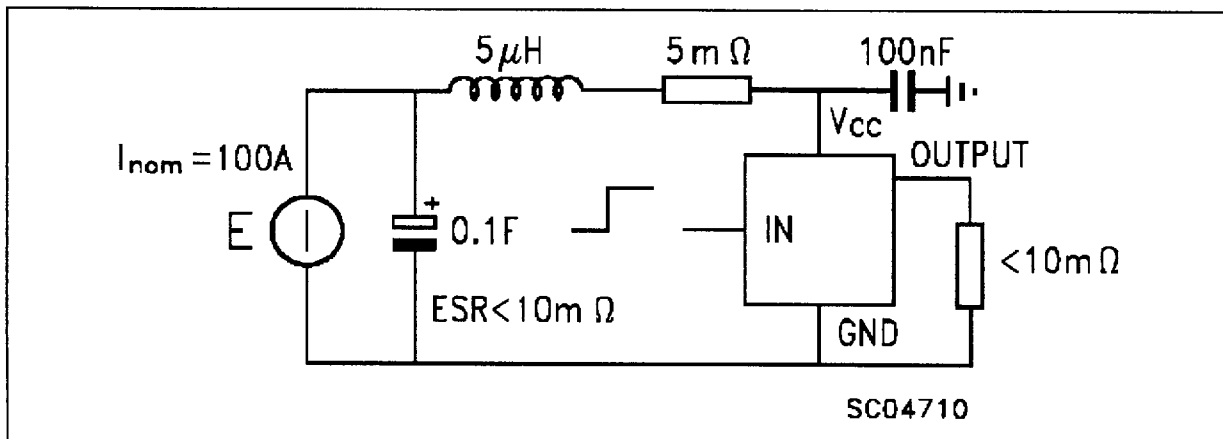


Figure 3: Typical Application Circuit With A Schottky Diode For Reverse Supply Protection

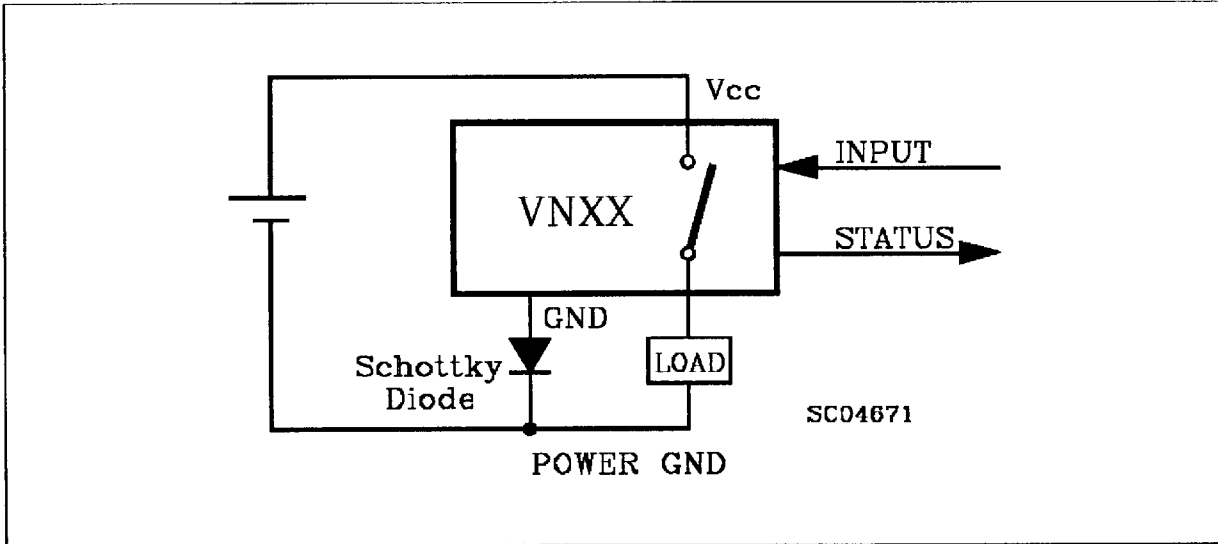
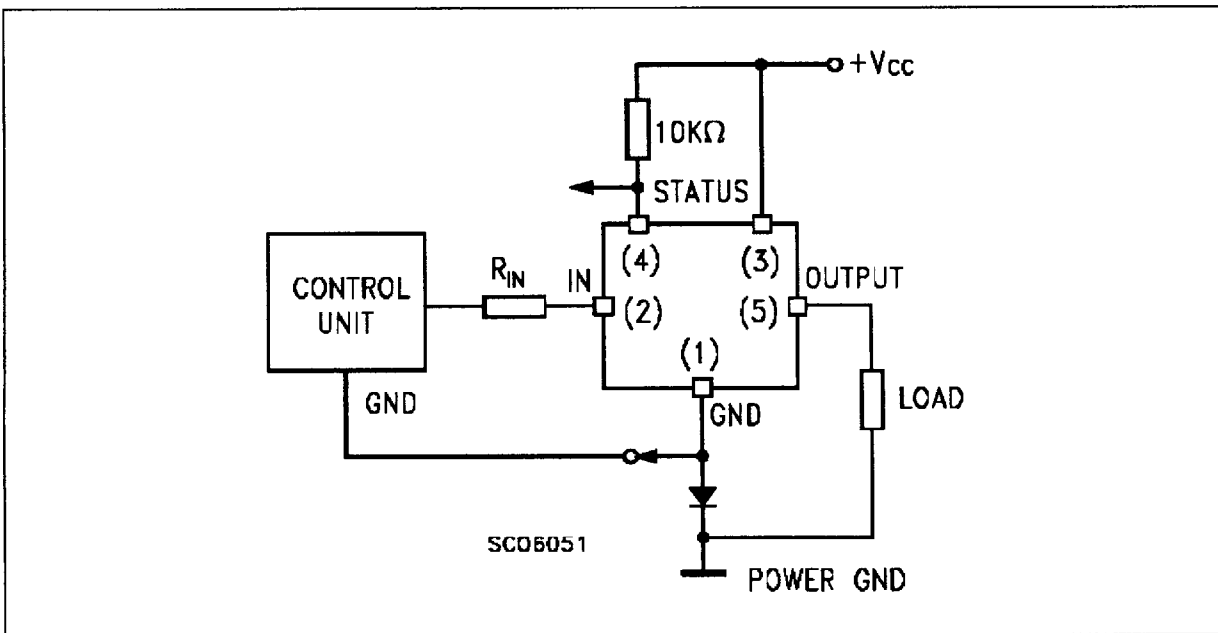
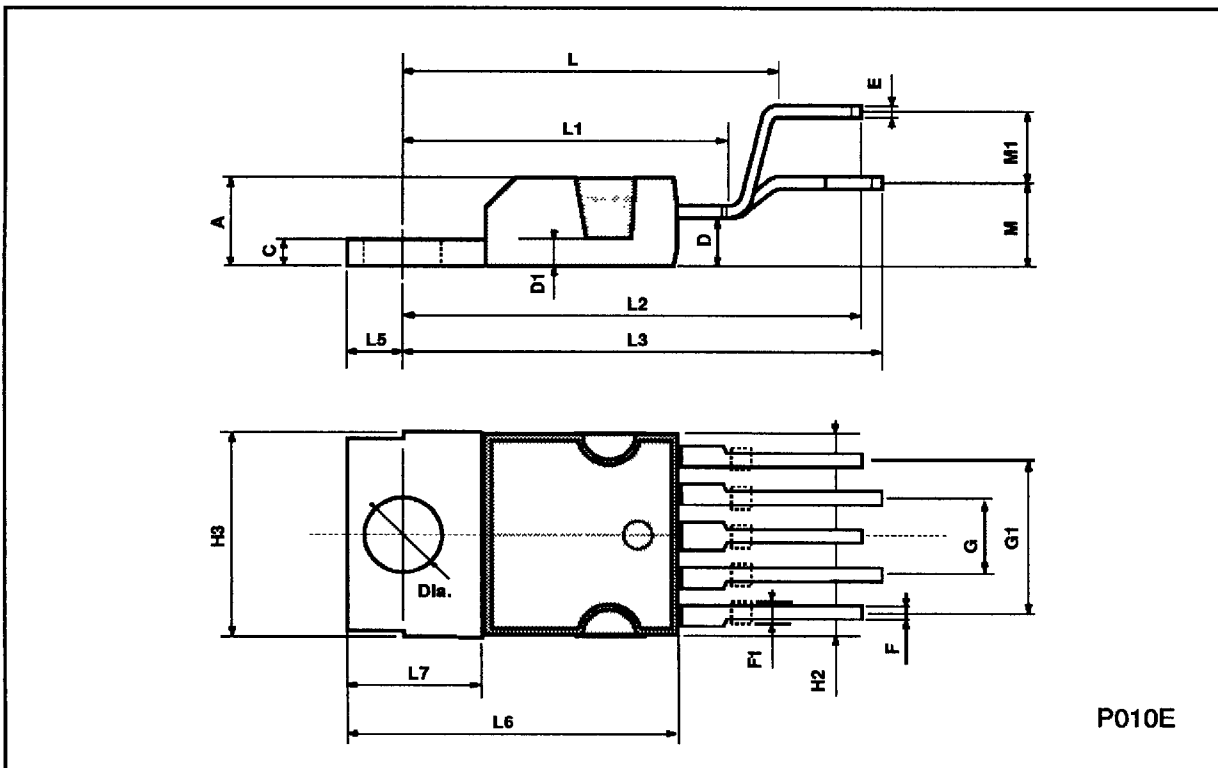


Figure 4: Typical Application Circuit With Separate Signal Ground



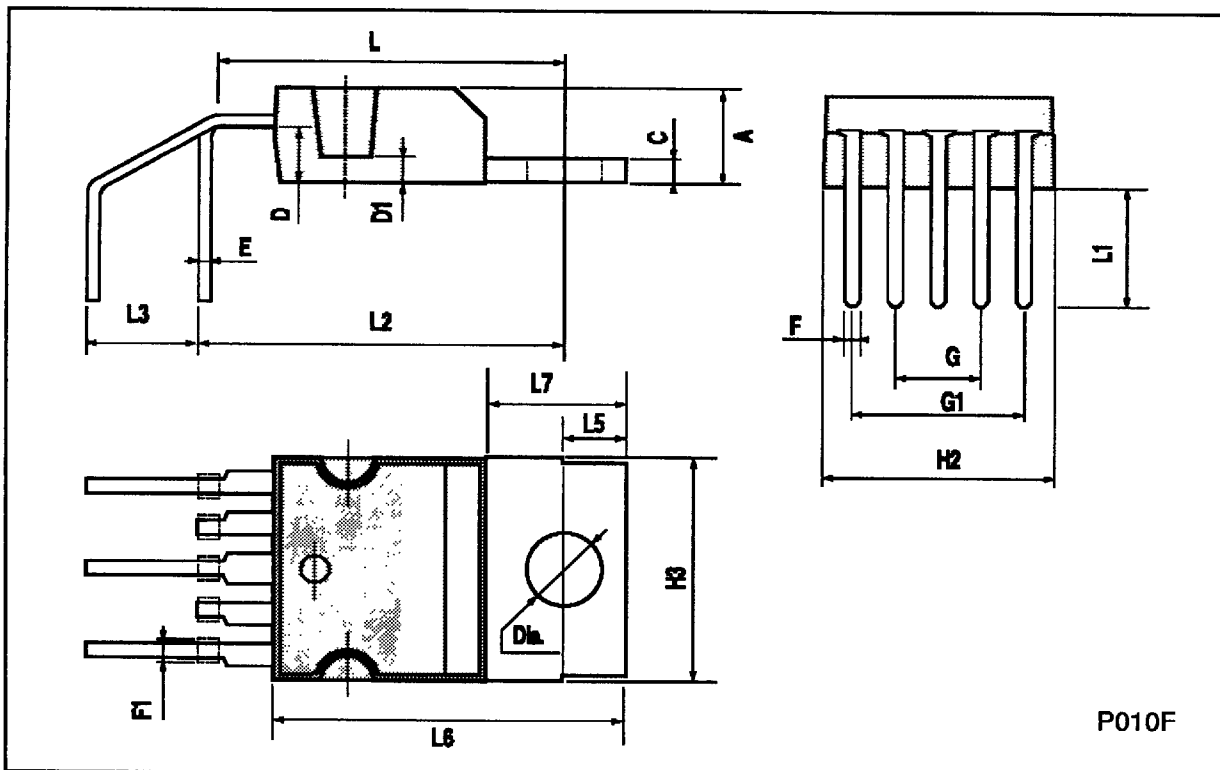
Pentawatt (vertical) MECHANICAL DATA

DIM.	mm			Inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			4.8			0.189
C			1.37			0.054
D	2.4		2.8	0.094		0.110
D1	1.2		1.35	0.047		0.053
E	0.35		0.55	0.014		0.022
F	0.8		1.05	0.031		0.041
F1	1		1.4	0.039		0.055
G	3.2	3.4	3.6	0.126	0.134	0.142
G1	6.6	6.8	7	0.260	0.268	0.276
H2			10.4			0.409
H3	10.05		10.4	0.396		0.409
L		17.85			0.703	
L1		15.75			0.620	
L2		21.4			0.843	
L3		22.5			0.886	
L5	2.6		3	0.102		0.118
L6	15.1		15.8	0.594		0.622
L7	6		6.6	0.236		0.260
M		4.5			0.177	
M1		4			0.157	
Dia	3.65		3.85	0.144		0.152



Pentawatt (horizontal) MECHANICAL DATA

DIM.	mm			Inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			4.8			0.189
C			1.37			0.054
D	2.4		2.8	0.094		0.110
D1	1.2		1.35	0.047		0.053
E	0.35		0.55	0.014		0.022
F	0.8		1.05	0.031		0.041
F1	1		1.4	0.039		0.055
G	3.2	3.4	3.6	0.126	0.134	0.142
G1	6.6	6.8	7	0.260	0.268	0.276
H2			10.4			0.409
H3	10.05		10.4	0.396		0.409
L	14.2		15	0.559		0.590
L1	5.7		6.2			0.244
L2	14.6		15.2			0.598
L3	3.5		4.1	0.137		0.161
L5	2.6		3	0.102		0.118
L6	15.1		15.8	0.594		0.622
L7	6		6.6	0.236		0.260
Dia	3.65		3.85	0.144		0.152



Pentawatt (In-Line) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			4.8			0.189
C			1.37			0.054
D	2.4		2.8	0.094		0.110
D1	1.2		1.35	0.047		0.053
E	0.35		0.55	0.014		0.022
F	0.8		1.05	0.031		0.041
F1	1		1.4	0.039		0.055
G	3.2	3.4	3.6	0.126	0.134	0.142
G1	6.6	6.8	7	0.260	0.268	0.276
H2			10.4			0.409
H3	10.05		10.4	0.396		0.409
L2	23.05	23.4	23.8	0.907	0.921	0.937
L3	25.3	25.65	26.1	0.996	1.010	1.028
L5	2.6		3	0.102		0.118
L6	15.1		15.8	0.594		0.622
L7	6		6.6	0.236		0.260
Dia	3.65		3.85	0.144		0.152

